SFF-TA-1023

Specification for

Thermal Characterization Specification for EDSFF E3 Devices

Rev 0.8.2  April 6th, 2021

SECRETARIAT: SFF TA TWG

This specification is made available for public review at http://www.snia.org/sff/specifications. Comments may be submitted at http://www.snia.org/feedback. Comments received will be considered for inclusion in future revisions of this specification.

The description of the connector in this specification does not assure that the specific component is available from connector suppliers. If such a connector is supplied, it should comply with this specification to achieve interoperability between suppliers.

ABSTRACT: This specification defines thermal performance measurement fixtures, methods, and reporting requirements for Enterprise/Datacenter Small Form Factor (EDSFF) E3 devices. EDSFF device thermal characteristics are influenced by the temperature and airflow velocity, enclosure design, workload and power requirements. To enable system integrators to comprehend whether a given device can be adequately cooled based on its dynamic operating conditions, this specification establishes a common method to characterize the variety of devices that may be developed.

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Thermal Specification for EDSFF Devices

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Foreword
The development work on this specification was done by the SNIA SFF TWG, an industry group. Since its formation as the SFF Committee in August 1990, the membership has included a mix of companies which are leaders across the industry.

For those who wish to participate in the activities of the SFF TWG, the signup for membership can be found at http://www.snia.org/sff/join.

Revision History

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<tr>
<th>Revision</th>
<th>Date</th>
<th>Description</th>
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<tr>
<td>Rev 0.1</td>
<td>August 13, 2020</td>
<td>Initial Draft</td>
</tr>
<tr>
<td>Rev 0.2</td>
<td>August 13, 2020</td>
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<tr>
<td>Rev 0.3</td>
<td>January 29th, 2021</td>
<td></td>
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<tr>
<td>Rev 0.4</td>
<td>February 2nd, 2021</td>
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<tr>
<td>Rev 0.5</td>
<td>February 3rd, 2021</td>
<td>added verbiage around Dtherm levels</td>
</tr>
<tr>
<td>Rev 0.6</td>
<td>February 4th, 2021</td>
<td>added developers note around intended use for Dtherm levels</td>
</tr>
<tr>
<td>Rev 0.7</td>
<td>February 26th, 2021</td>
<td>Refined recommended design space, added UUT definition</td>
</tr>
<tr>
<td>Rev 0.8</td>
<td>March 17th, 2021</td>
<td>Refined MaxTherm/Dtherm measurement requirements, specifically allowing for analytical temperature scaling based on device thermal margin. Clarified that Dtherm levels should correlate to NVMe power states for E3 NVMe use cases. Clarified that in the 6xE3 thin test case, only 3 adjacent devices need to be functional and stressed for thermal measurement. Updated the E3.S 1T recommended design space.</td>
</tr>
<tr>
<td>Rev 0.8.1</td>
<td>April 9th, 2021</td>
<td>Corrected Table 4-3 to show Y axis as Channel Velocity (LFM). Updated Figure 4-1 to represent the larger range indicated by the equations in Table 4-1. Added a note that AFI static pressure and airflow measurements should be corrected to sea level altitude and 25C ambient temperature.</td>
</tr>
<tr>
<td>Rev 0.8.2</td>
<td>April 6th, 2021</td>
<td>Added Table 5-1, which provides a template for device makers to show device power and performance at MaxTherm and Dtherm levels, as well as other parameters relevant to E3 thermal performance. Added a detailed description and equation in Section 5 for analytical temperature scaling in the test fixture during MaxTherm/Dtherm testing.</td>
</tr>
</tbody>
</table>
Contents

1. References and Conventions
   1.1. Industry Documents
   1.2. Sources
   1.3. Conventions

2. Keywords, Acronyms, and Definitions
   2.1. Keywords
   2.2. Acronyms and Abbreviations
   2.3. Definitions

3. EDSFF Device Thermal Reporting
   3.1. Overview
   3.2. Airflow Impedance (AFI) Level
   3.3. Maximum Thermal (MaxTherm) Level
   3.4. Degraded Thermal (DTherm) Level
   3.5. MaxAmbient

4. Thermal Data Collection and Test Procedure
Figures

1. Figure 3-1: AFI Levels
2. Figure 3-2: MaxTherm and Dtherm Levels
3. Figure 3-3: Example Device Thermal Profile
4. Figure 4-1: Airflow Chamber
5. Figure 4-2: E3 2t Test Fixture and Device Setup
6. Figure 4-3: E3 1t Test Fixture
7. Figure 4-4: Required Dimensions of E3 1t test fixture
8. Figure 4-5: Required Dimensions of E3 2x test fixture
9. Figure 4-6: Maximum Test Cabling Keep-in dimensions
10. Figure 4-7: Actual Thermal Level Test Fixture Set-up
11. Table 3-1: AFI Level Equations
12. Table 3-2: Thermal Level Equations (CFM/Device)
13. Table 3-3: Thermal Level Equations (Test Fixture Channel Velocity (LFM))
14. Table 4-1: Device Thermal Performance Template
1. References and Conventions

1.1. Industry Documents
The following documents are relevant to this specification:
- ASME Y14.5 Dimensioning and Tolerancing
- REF-TA-1011 Cross Reference to Select SFF Connectors
- SFF-TA-1002 Protocol Agnostic Multi-Lane High Speed Connector
- SFF-TA-1006 Enterprise and Datacenter 1U Short SSD Form Factor (E1.S)
- SFF-TA-1008 Enterprise and Datacenter SSD 3" Form Factor (E3)

1.2. Sources
The complete list of SFF documents which have been published, are currently being worked on, or that have been expired by the SFF Committee can be found at http://www.snia.org/sff/specifications. Suggestions for improvement of this specification will be welcome, they should be submitted to http://www.snia.org/feedback.
Copies of ASME standards may be obtained from the American Society of Mechanical Engineers (https://www.asme.org).
Copies of Electronic Industries Alliance (EIA) standards may be obtained from the Electronic Components Industry Association (ECIA) (https://www.ecianow.org).
1.3. **Conventions**

The following conventions are used throughout this document:

**DEFINITIONS**

Certain words and terms used in this standard have a specific meaning beyond the normal English meaning. These words and terms are defined either in the definitions or in the text where they first appear.

**ORDER OF PRECEDENCE**

If a conflict arises between text, tables, or figures, the order of precedence to resolve the conflicts is text; then tables; and finally figures. Not all tables or figures are fully described in the text. Tables show data format and values.

**LISTS**

Lists sequenced by lowercase or uppercase letters show no ordering relationship between the listed items.

**EXAMPLE 1** - The following list shows no relationship between the named items:

- red (i.e., one of the following colors):
  - A. crimson; or
  - B. pink;
- blue; or
- green.

Lists sequenced by numbers show an ordering relationship between the listed items.

**EXAMPLE 2** - The following list shows an ordered relationship between the named items:

1. top;  
2. middle; and  
3. bottom.

Lists are associated with an introductory paragraph or phrase, and are numbered relative to that paragraph or phrase (i.e., all lists begin with an a. or 1. entry).

**DIMENSIONING CONVENTIONS**

The dimensioning conventions are described in ASME Y14.5, Geometric Dimensioning and Tolerancing. All dimensions are in millimeters, which are the controlling dimensional units (if inches are supplied, they are for guidance only).

**NUMBERING CONVENTIONS**

The ISO convention of numbering is used (i.e., the thousands and higher multiples are separated by a space and a period is used as the decimal point). This is equivalent to the English/American convention of a comma and a period.

<table>
<thead>
<tr>
<th>American</th>
<th>French</th>
<th>ISO</th>
</tr>
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<td>0.6</td>
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<td>1,000</td>
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<tr>
<td>1,323,462.9</td>
<td>1 323 462,9</td>
<td>1 323 462.9</td>
</tr>
</tbody>
</table>
2. Keywords, Acronyms, and Definitions

For the purposes of this document, the following keywords, acronyms, and definitions apply.

2.1. Keywords

May/ may not: Indicates flexibility of choice with no implied preference.

Obsolete: Indicates that an item was defined in prior specifications but has been removed from this specification.

Optional: Describes features which are not required by the SFF specification. However, if any feature defined by
the SFF specification is implemented, it shall be done in the same way as defined by the specification. Describing
a feature as optional in the text is done to assist the reader.

Prohibited: Describes a feature, function, or coded value that is defined in a referenced specification to which this
SFF specification makes a reference, where the use of said feature, function, or coded value is not allowed for
implementations of this specification.

Reserved: Defines the signal on a connector contact [when] its actual function is set aside for future
standardization. It is not available for vendor specific use. Where this term is used for bits, bytes, fields, and code
values; the bits, bytes, fields, and code values are set aside for future standardization. The default value shall be
zero. The originator is required to define a Reserved field or bit as zero, but the receiver should not check Reserved
fields or bits for zero.

Restricted: Refers to features, bits, bytes, words, and fields that are set aside for other standardization purposes.
If the context of the specification applies the restricted designation, then the restricted bit, byte, word, or field shall
be treated as a reserved bit, byte, word, or field (e.g., a restricted byte uses the same value as defined for a
reserved byte).

Shall: Indicates a mandatory requirement. Designers are required to implement all such mandatory requirements
to ensure interoperability with other products that conform to this specification.

Should: Indicates flexibility of choice with a strongly preferred alternative.

Vendor specific: Indicates something (e.g., a bit, field, code value) that is not defined by this specification.
Specification of the referenced item is determined by the manufacturer and may be used differently in various
implementations.

2.2. Acronyms and Abbreviations

E1: Form factors and devices defined in SFF-TA-1006
E3: Form factors and devices defined in SFF-TA-1008
EDSFF: Enterprise/Datacenter Small Form Factor
2.3. Definitions

AFI Level – Air Flow Impedance Curve

MaxTherm Level - Minimum airflow required at a given approach air temperature for which a device at TDP level limit will operate and without degraded performance. TDP refers to ‘Thermal Design Power’, which is the maximum amount of heat generated by the device under load.

DTherm Level - Minimum airflow required at a given approach air temperature for which a device will operate but at a reduced device performance level. More than one Dtherm level can be set for a device under different performance modes.

MaxAmbient - Approach air temperature upper threshold if required by a device (for example, some devices may not be designed to operate above 60 °C)

Approach Air Temperature – Average temperature of the air before it reaches the EDSFF devices

Channel Velocity – Velocity of air when traveling in the gaps between the EDSFF drives. See Section 5.

3. EDSFF Device Thermal Reporting

3.1. Overview

This document defines thermal characterization and parameter reporting for EDSFF E3 devices and describes the test and modelling procedure for the measurement of thermal and airflow impedance of an array of devices. Using this framework, specific implementations of EDSFF devices may be characterized and their parameters communicated effectively to enable system integrations.

Thermal Reporting uses three metrics that characterize the device airflow impedance levels and cooling requirements. These metrics are AFI, MaxTherm, and DTherm. The metrics allow devices to be classified into groups so that system designers may select devices that are compatible with their host systems. In addition, system BMC software may read the metrics from the device and utilize that information to set appropriate fan speeds. Device designers are encouraged to utilize the metrics and work with system designers to ensure that the devices being developed, and their associated metrics are aligned with system capabilities.

3.2. Airflow Impedance (AFI) Level

The intent of Airflow Impedance Level information is to classify devices into groups based on their impedance to airflow. These groups are referred to as AFI levels for the purpose of this specification. The AFI level is an important parameter for system designers due to the impact to airflow a high impedance device may have versus a low impedance device. The AFI level is important for system cooling as well as individual device cooling. The installation of higher impedance devices, especially if multiple such devices are installed, in a platform may exceed the capabilities for a given platform fan performance curve. Through testing, system developers determine which device AFI levels a platform can support. The AFI level may also be used in real time by system fan control algorithms to manipulate fan speeds based on the AFI reported by the devices.

The test procedure for determining the AFI level is defined in Section 5. Device impedance is categorized as one of 6 levels communicated by the AFI level field. Each AFI level corresponds to one of the curves illustrated in Figure 3-1. The AFI Level field is reported as a value of one through six.
A device is assigned to an AFI level by comparing its measured impedance within the range of 0 to 10 CFM per device to the AFI Level equations listed in Table 3-1. The device is assigned the highest of the AFI levels intersected by the device impedance curve. The airflow vs static pressure measurements used to characterize a device’s AFI level should be corrected to equivalent values at sea level and 25°C if the test is conducted at a different altitude or ambient temperature.

Table 3-1: AFI Level Equations

<table>
<thead>
<tr>
<th>AFI Level</th>
<th>Equation (X=volumetric airflow [CFM]; Y=static pressure [in.w.g.])</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>Reserved</td>
</tr>
<tr>
<td>1</td>
<td>$Y = 0.00893 \times X^2 + 0.01857 \times X$</td>
</tr>
<tr>
<td>2</td>
<td>$Y = 0.01785 \times X^2 + 0.03713 \times X$</td>
</tr>
<tr>
<td>3</td>
<td>$Y = 0.02678 \times X^2 + 0.05570 \times X$</td>
</tr>
<tr>
<td>4</td>
<td>$Y = 0.03570 \times X^2 + 0.07427 \times X$</td>
</tr>
<tr>
<td>5</td>
<td>$Y = 0.04463 \times X^2 + 0.09283 \times X$</td>
</tr>
<tr>
<td>6</td>
<td>$Y = 0.05355 \times X^2 + 0.11140 \times X$</td>
</tr>
</tbody>
</table>

3.3. Maximum Thermal (MaxTherm) Level

The intent of the Maximum Thermal (MaxTherm) Level information is to define the minimum airflow rate required at a given air temperature for which a device, when stressed to its TDP (thermal design power) level limit, will operate within its component’s reliability limits and without degraded device performance. Once a device’s thermal performance profile is established, the MaxTherm Level is determined. MaxTherm is the lowest curve in Figure 3-2 which is entirely above the device’s quantified thermal performance curve throughout the range of approach ambient temperatures (also referred to as approach temperature) illustrated on the X-axis ranging from 25 °C up to 65 °C.
Airflow and thermal measurement shall be performed in the thermal test fixture defined in Section 5. The general process to determine the MaxTherm Level is as follows:

1. Setup drives in test fixture with cables or backplane connecting devices to host system or controller
2. Set flow bench or wind tunnel to appropriate airflow setting for desired measurement point
3. Initiate device stress required to achieve the maximum device TDP
4. Allow device temperatures to reach steady state
5. Collect device temperatures in addition to local approach temperature and airflow measurements
6. Approach temperature and measured device temperatures are scaled up until the first device (with the lowest thermal margin) reaches its maximum component temperature. This approach temperature and airflow rate (per device) pair is one point on the device cooling curve. This temperature scaling can be performed experimentally via heating the approach air, or analytically by keeping approach air temperature constant and using remaining thermal margin to determine the maximum allowable approach temperature for a given flowrate. For a detailed explanation of analytical approach air temperature scaling, see Section 5.
7. Repeat for other airflow rates as appropriate to develop the complete device cooling curve
8. The device cooling curve (required CFM/device vs. local approach temperature) is plotted against the predefined MaxTherm levels shown in Figure 3-2. The device MaxTherm level is the lowest curve in Figure 4-2 which is entirely above the device cooling curve throughout the range of approach temperatures illustrated on the X-axis ranging from 25 °C up to 65 °C.

Note that airflow is recorded as CFM/device, but channel velocity can be calculated easily for uniformly shaped devices using the function defined in Section 5. The thermal levels defined in Figure 3-2 display CFM/dev on the left-hand Y-axis, and channel velocity (in the test fixture) on the right-hand Y-axis. Calculating channel velocity may allow more accurate predictions of drive performance in system slots, as drive pitch and drive thickness can vary. Note that the recommended design space for E3.S 1T devices is shown in the shaded region on the chart. For E3.S 1T devices, the recommended design space is below Level 3, up to 60C approach velocity. The recommended design space for E3.S 2T devices is TBD.

- Curves in Figure 3-2 are shown for illustrating the recommended design space.
- Compare measured readings against the equations defined in Error! Reference source not found.
- Thermal Levels 3-8 do not require a device to support less than 1.5 CFM.

**Developer Note:** It is strongly recommended that developers strive to offer solutions that can operate within the shaded recommended design space envelope illustrated in Figure 3-2 to maximize the number of systems that can support such conditions.

The MaxTherm field is defined for a value of 1 through 8.
No lower flow rates shall be presumed for approach air temperatures below 25 °C.

As an example of proper E3 test fixture usage, Figure 3-3 illustrates the curve of a hypothetical device that has been tested. The highlighted circle illustrates that the UUT (Unit Under Test) exceeds MaxTherm Level 1 above an approach air temperature of 30 °C. Given this example device cooling curve, MaxTherm Level 2 would be selected for this device.
### Table 3-2: Thermal Level Equations (CFM/Device)

<table>
<thead>
<tr>
<th>AFI Level</th>
<th>X = Approach Temperature; Y = Airflow Required (CFM/Device)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>Reserved</td>
</tr>
<tr>
<td>1*</td>
<td>Y = 0.3416 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>2*</td>
<td>Y = 0.5214 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>3**</td>
<td>Y = 0.6832 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>4</td>
<td>Y = 0.9042 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>5</td>
<td>Y = 1.0689 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>6</td>
<td>Y = 1.2828 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>7</td>
<td>Y = 1.5394 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>8</td>
<td>Y = 1.8472 * e^(0.0365 * X)</td>
</tr>
</tbody>
</table>

**Note**: Approach air speed values for indicated Thermal Levels shall not be less than 100 LFM.

**Note**: Level 3 is the recommended design space limit for E3.S1T devices.

### Table 3-3: Thermal Level Equations (Test Fixture Channel Velocity (LFM))

<table>
<thead>
<tr>
<th>AFI Level</th>
<th>X = Approach Temperature; Y = Airflow Required (Channel Velocity - LFM)</th>
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</thead>
<tbody>
<tr>
<td>0</td>
<td>Reserved</td>
</tr>
<tr>
<td>1*</td>
<td>Y = 231.98 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>2*</td>
<td>Y = 347.98 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>3</td>
<td>Y = 463.97 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>4</td>
<td>Y = 614.07 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>5</td>
<td>Y = 725.97 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>6</td>
<td>Y = 871.17 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>7</td>
<td>Y = 1045.4 * e^(0.0365 * X)</td>
</tr>
<tr>
<td>8</td>
<td>Y = 1254.5 * e^(0.0365 * X)</td>
</tr>
</tbody>
</table>
3.4. Degraded Thermal (DTherm) Level

The intent of the Degraded Thermal (DTherm) Level information is to determine the minimum airflow required at a given air temperature for which a device will operate within its component's reliability limits but at a degraded device performance level. The stress application that was used for MaxTherm is also used for DTherm. Typically, the degraded performance is induced by the device’s self-initiated thermal protection schemes, such as throttling. This is of interest for platforms unable to provide sufficient cooling, such as due to the loss of a cooling fan which reduces the platform’s cooling capacity. The reduced cooling capacity in such a case may be below the device MaxTherm Level.

If a device can operate at a reduced performance level to protect itself thermally and this translates into a reduced thermal profile from that established for MaxTherm, then DTherm is not equal to MaxTherm. DTherm is calculated using the same process as MaxTherm, however, the device’s profile is created using the device’s most reduced performance operating level at which it is still operating and providing useful work as defined by the device implementer. The number of reported DTherm levels are up to the device implementer based on software definition and numbers of operating states. DTherm reporting is strongly recommended as this information allows system integrators to understand performance throttling options to balance performance with available system cooling. Drives may be set to run continuously in a Dtherm level or be allowed to self-regulate Dtherm levels based on available cooling. Dtherm levels should be used to represent an E3 device in different NVMe power states for NVMe E3 use cases.

Developer Note: It is strongly recommended that developers strive to achieve better thermal performance by establishing multiple Dtherm levels. Not all slots in all systems will be optimally located for E3 device cooling; creating a means for a device to function (even in a degraded state) in a wide variety of approach temperatures and flow rates ensures that the device can be used broadly across a server portfolio. For instance, a device will have a Maxtherm level representing thermal performance at TDP and maximum bandwidth but should also have multiple Dtherm levels beneath this showing improved thermal performance at reduced bandwidth and device power. The device should be able to switch to a Dtherm level of performance automatically in the event of a thermal excursion but should also contain a means by which the controller can initiate a Dtherm level limit for the device. An example of proper Dtherm usage would be as follows: Maxtherm represents 100% bandwidth, Dtherm 1 represents 75%, Dtherm 2 represents 50%, Dtherm 3 represents 25%, Dtherm 4 represents maximum throttled condition while still providing useful performance. These Dtherm levels should correspond to NVMe power states for storage devices.

3.5. MaxAmbient

Some devices may not be thermally viable up to an approach air temperature of 65 °C, regardless of the air speed involved. Or, even if the device could be thermally viable at high temperature extremes, the airflow requirements to do so may require it to operate at a higher thermal challenge level, potentially reducing the number of systems able to supply the needed airflow. In either circumstance, the device may opt to have its upper approach air temperature limit be less than 65 °C. This approach air temperature upper threshold is referred to as MaxAmbient and is defined as the temperature just below or at a throttling condition. MaxAmbient shall be an integer value between 50 °C and 65 °C inclusive. Max Ambient applies to the full operating potential MaxTherm condition.
4. Thermal Data Collection and Test Procedure

The following specifies the thermal test set-up and procedure to evaluate an EDSFF device's thermal performance. As previously discussed, thermal performance is partitioned into four sub-fields:

- AFI Level – Air Flow Impedance Curve
- MaxTherm Level - Minimum airflow required at a given air temperature for which a device at TDP level limit will operate and without degraded performance
- DTherm Level - Minimum airflow required at a given air temperature for which a device, when provided the same stress application as it was for MaxTherm, will operate but at a degraded device performance level
- MaxAmbient - Approach air temperature upper threshold between 50 °C and 65 °C if required by a device

The values of these fields are determined using the test fixture. Details regarding the dimensions and construction of the test fixture are provided in this specification along with the associated CAD files (contained in the SFF-TA-1023.zip file from SNIA). These four sub fields should be used to populate Table 4-1 for the unit under test:

<table>
<thead>
<tr>
<th>Table 4-1: Device Thermal Performance Template</th>
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<tbody>
<tr>
<td>Device Form Factor:</td>
</tr>
<tr>
<td>Device AFI Level</td>
</tr>
<tr>
<td>Device Max Ambient</td>
</tr>
<tr>
<td></td>
</tr>
<tr>
<td>MaxTherm</td>
</tr>
<tr>
<td>Dtherm1</td>
</tr>
<tr>
<td>Dtherm2</td>
</tr>
<tr>
<td>Dtherm3</td>
</tr>
<tr>
<td>Dtherm4</td>
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<tr>
<td>Dtherm5</td>
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<tr>
<td>As Needed</td>
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<tr>
<td></td>
</tr>
<tr>
<td>Device Power (W)</td>
</tr>
<tr>
<td>-----------------------------------------------</td>
</tr>
</tbody>
</table>

The test fixture is intended to be attached to an AMCA 210-99/ASHRAE 51-1999 compliant airflow chamber, an example of which is shown in Figure 4-1, which can quantify both static pressure as well as volumetric airflow.

Figure 4-1: Airflow Chamber

Thermal Specification for EDSFF Devices
The tester is attached to the airflow chamber such that ambient air is pulled into the fixture from the LED facing side of the device. When performing airflow impedance tests to determine the AFI level only the devices should be installed into the fixture. No backplane or cables should be included. Airflow set points for AFI levels are 2, 4, 6, 8, and 10 CFM per device. Thus for the 3 devices fixture the airflow points are 12, 18, 24, and 30 CFM. For the 6x thin device fixture the airflow points are 24, 36, 48, and 60 CFM. At each airflow point the static pressure at the flow bench is collected in units of inches of water (in. w.g.).

Additionally, Channel Velocity can be calculated to aid in system design. As drive pitch and thickness can vary from system to system, channel velocity can be used in place of CFM/device for regularly shaped devices without extended fin surfaces. Channel velocity can be calculated easily as follows:

\[
\text{Channel Velocity (LFM)} = \frac{\text{CFM}}{(\text{Drive Pitch (mm)} - \text{Drive Thickness (mm)}) \times \text{Drive Width (mm)}} \times 92903
\]

For example, channel velocity in the test fixture for a 7.5mm thick device at 2.5 CFM/dev would follow:

\[
\text{Channel Velocity (LFM)} = \frac{2.5 \times 92903}{(9.3\text{mm} - 7.5\text{mm}) \times 76\text{mm}} = 1697 \text{ LFM}
\]

Here, channel velocity is defined as the gap between two uniformly shaped EDSFF drives. The thermal levels defined in Figure 3-2 display CFM/dev on the left-hand Y-axis, and channel velocity (in the test fixture) on the right-hand Y-axis. Calculating channel velocity may allow more accurate predictions of drive performance in system slots, as drive pitch and drive thickness can vary.

When testing to determine the MaxTherm or DThermal levels the test fixture and device to be tested must be setup according to this specification. As with the AFI level testing, the tester is attached to the airflow chamber such that ambient air is pulled into the fixture from the LED facing side of the device. Identical devices must be installed in the slots adjacent to the device under test. All cables needed to fully exercise the three devices are attached to the devices and routed outside the system to minimize the blockage of airflow. While the E3 1T test fixture can hold up to 6 devices, only 3 adjacent devices needed to be stressed for each measurement. The 3 devices not stressed need to share the same geometry with those being stressed so that airflow is uniform through the drives. For example, in Figure 4-3 only UUT, Drive 1 and Drive 2 need to be functioning devices; the other drives can be nonfunctioning representations of the UUT. The test fixture’s lid is attached, and the test fixture is checked to ensure air flow is not leaking through its joints, cable egress locations, or at interface with the flow chamber.

The device under test and each adjacent identical device is operated to its rated maximum TDP level using an appropriate device stress test procedure. The device manufacturer should provide sufficient detail including software, firmware, and hardware required such that system integrators could recreate the same results if provided the same device. The following figures beginning with Figure 4-2 illustrate the test fixtures for E3 devices.
Figure 4-2: E3 2t Test Fixture and Device Setup
The test fixture design features are specified to ensure interoperability with E3 devices and consistent measurement. The following figures illustrate these interoperability points.

Figure 4-3: E3 1t Test Fixture
Commented [BJ1]: The width between ribs, specified as 7.56mm, is not large enough to accommodate an E3.1T at maximum material condition.
Figure 4-5: Required Dimensions of E3 2x test fixture
Figure 4-6: Required Dimensions of E1.S 9.5mm test fixture
Figure 4-7: Required Dimensions of E1.S 15mm test fixture
Figure 4-8: Required Dimensions of E1.S 25mm test fixture
Figure 4-9: Required Dimensions of E1.L 9.5mm test fixture
A system board with enough slots to operate each device in the fixture at maximum link width and maximum link speed is needed for testing. The device and system board shall be configured to operate at their maximum performance level. The platform power supply shall be capable of supplying the power required for the system board and the device to run at their highest performance levels. The following figures illustrate a cabling keep in for connector to devices.

**Figure 4-10:** Required Dimensions of E1.L 18mm test fixture
For MaxTherm and DTherm testing, the quantified volumetric airflow per device is reported.

At least one thermocouple sensor shall be placed to collect inlet air temperature data no less than 5mm from the inlet and no more than 4mm from the front of the device under test. Another thermocouple sensor shall be placed on the device under test to monitor critical local temperature. The location of local temperature measurement is defined by the implementer and should be reported in addition to thermal parameters. Figure 4-7 illustrates an example test setup connected to a flow bench.

Commented [B32]: Need to add X8 connector keep-in requirements for E1.X form factor.
To evaluate the device cooling parameters (MaxTherm and Dtherm), the approach air temperature can be scaled experimentally or analytically. Experimental air temperature scaling requires a heated flowbench, but analytical temperature scaling can be performed at room temperature. To perform analytical temperature scaling, use the equation as follows:

$$\text{Scaled Device Temperature} = (\text{Desired Scaled Approach Temperature} - \text{Approach Air Temperature}) + \text{Device Temperature}$$

For example, if the thermal limiting component on the UUT (Unit Under Test) is at 48°C when flowrate is held constant at 2 CFM/dev, and the approach air temperature is 24°C, we could scale the device temperature up as if the approach air temperature was 40°C (or any other value chosen):

$$64°C = (40°C - 24°C) + 48°C$$

The device temperature at 2 CFM/dev and 40°C approach would be 64°C in this instance. Using this method, and the thermal Tcase limit for the limiting component, the theoretical maximum approach temperature can be calculated at each flowrate for the different workloads associated with MaxTherm and Dtherm.